IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the Application of

Shinya ARASE, Takahiro KISHIOKA, Ken-ichi MIZUSAWA

Application No.: New U.S. Patent Application

Filed: February 20, 2002 Docket No.: 111993

For: BOTTOM ANTI-REFLECTIVE COAT FORMING COMPOSITION FOR

LITHOGRAPHY

PRELIMINARY AMENDMENT

Director of the U.S. Patent and Trademark Office Washington, D. C. 20231

Sir:

Prior to initial examination, please amend the above-identified application as follows:

IN THE CLAIMS:

Please replace claims 6,7,8 and 9 as follows:

- 6. (Amended) The bottom anti-reflective coat forming composition according claim 3, wherein R¹ is hydrogen, halogen or substituted or unsubstituted C₁-C₁₀ alkyl group in the structural unit shown in the Formula (1) or the Formula (2).
- 7. (Amended) The bottom anti-reflective coat forming composition according to claim 1, wherein said composition further comprises crosslinking agent having at least two crosslinking forming functional groups.
- (Amended) The method of forming the bottom anti-reflective coating for the lithography process in the preparation of semiconductor device, comprising applying the

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bottom anti-reflective coat forming composition according to claim 1 over the substrate, and then baking.

9. (Amended) The method of preparation for semiconductor device, comprising applying the bottom anti-reflective coat forming composition according to claim 1 over the substrate, forming the bottom anti-reflective coating upon baking, coating photoresist over said bottom anti-reflective coating, exposing said substrate, developing and forming integrated circuit elements after transferring the image over the substrate by etching.

REMARKS

Claims 1-10 are pending. By this Preliminary Amendment, claims 6,7,8 and 9 are amended to remove multiple dependencies. Prompt and favorable examination on the merits is respectfully requested.

The attached Appendix includes marked-up copies of each rewritten claim (37 C.F.R. 1.121(c)(1)(ii)).

Respectfully submitted,

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JAO:JSA/mlb Attached: Appendix Date: February 20, 2002

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APPENDIX

Changes to Claims:

The following are marked-up versions of the amended claims:

- 6. (Amended) The bottom anti-reflective coat forming composition according claim 3 to any one of claims 3 to 5, wherein R¹ is hydrogen, halogen or substituted or unsubstituted C₁-C₁₀ alkyl group in the structural unit shown in the Formula (1) or the Formula (2).
- 7. (Amended) The bottom anti-reflective coat forming composition according to claim lany one of claims 1 to 6, wherein said composition further comprises crosslinking agent having at least two crosslinking forming functional groups.
- 8. (Amended) The method of forming the bottom anti-reflective coating for the lithography process in the preparation of semiconductor device, comprising applying the bottom anti-reflective coat forming composition according to claim 1 any one of claims 1 to 7 over the substrate, and then baking.
- 9. (Amended) The method of preparation for semiconductor device, comprising applying the bottom anti-reflective coat forming composition according to <u>claim 1 anyone of claims 1 to 7</u> over the substrate, forming the bottom anti-reflective coating upon baking, coating photoresist over said bottom anti-reflective coating, exposing said substrate, developing and forming integrated circuit elements after transferring the image over the substrate by etching.